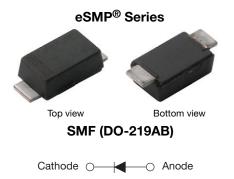
### **Vishay Semiconductors**

Hyperfast Rectifier, 1 A FRED Pt<sup>®</sup>



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DESIGN SUPPORT TOOLS



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	1 A			
V <sub>R</sub>	100 V			
V <sub>F</sub> at I <sub>F</sub> (typ. 125 °C)	0.74 V			
t <sub>rr</sub>	25 ns			
T <sub>J</sub> max.	175 °C			
Package	SMF (DO-219AB)			
Circuit configuration	Single			

#### FEATURES

- Hyperfast recovery time, reduced Q<sub>rr</sub>, and soft recovery
- 175 °C maximum operating junction temperature
- Specified for output and snubber operation
- Low forward voltage drop
- · Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Wave and reflow solderable
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in snubber, boost, lighting, piezo-injection, as high frequency rectifiers, and freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage	V <sub>RRM</sub>		100	V			
Average rectified forward current	I <sub>F(AV)</sub>	$T_{\rm C} = 160 \ ^{\circ}{\rm C} \ ^{(1)}$	1	٨			
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	35	A			
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C			

Note

<sup>(1)</sup> Device on PCB with 8 mm x 16 mm soldering lands

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	100	-	-	v	
Forward voltage		I <sub>F</sub> = 1 A	-	0.87	0.93		
	V <sub>F</sub>	I <sub>F</sub> = 1 A, T <sub>J</sub> = 125 °C	-	0.74	0.8		
			-	-	2		
Reverse leakage current I <sub>R</sub>		$T_J = 125 \ ^{\circ}C, V_R = V_R \text{ rated}$	-	0.5	8	μA	
Junction capacitance	CT	V <sub>R</sub> = 100 V	-	5	-	pF	

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}$	Vµs, V <sub>R</sub> = 30 V	-	24	-	
Poweree recevery time	+	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A, I <sub>rr</sub> = 0.25 A		-	-	25	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	16	-	ns
		T <sub>J</sub> = 125 °C		-	23	-	
Deck receiver a urrent		T <sub>J</sub> = 25 °C	$I_F = 1 A$	-	1.6	-	
Peak recovery current	IRRM	T <sub>J</sub> = 125 °C	dl <sub>F</sub> /dt = 200 A/µs V <sub>R</sub> = 160 V	-	2.5	-	A
Reverse recovery charge		T <sub>J</sub> = 25 °C	1	-	13	-	nC
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	30	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	+175	°C
Thermal resistance, junction to case	R <sub>thJC</sub>	Device mounted on PCB with 8 mm x 16 mm soldering lands	-	-	17	°C/W
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Device mounted on PCB with 2 mm x 3.5 mm soldering lands	-	-	140	°C/W
Approximate weight				0.015		g
Approximate weight				0.0005		oz.
Marking device		Case style SMF (DO-219AB)		M	AH	

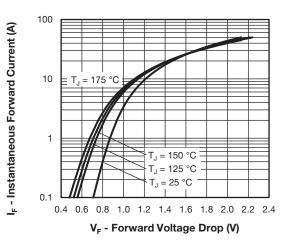


Fig. 1 - Typical Forward Voltage Drop Characteristics

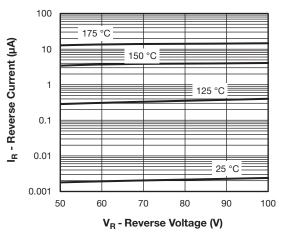
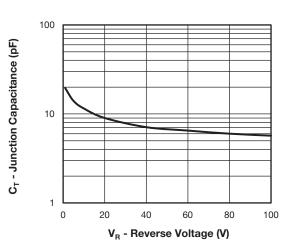


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

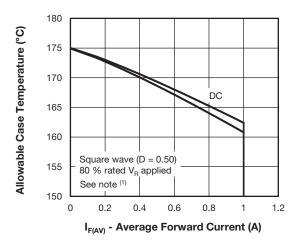


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

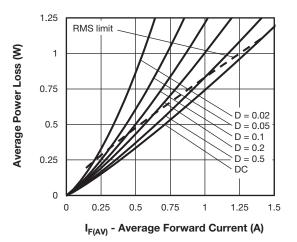


Fig. 5 - Forward Power Loss Characteristics

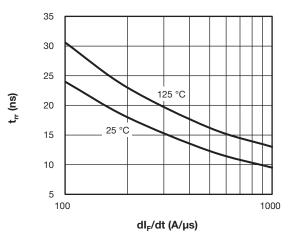


Fig. 6 - Typical Reverse Recovery Time vs. dI<sub>F</sub>/dt

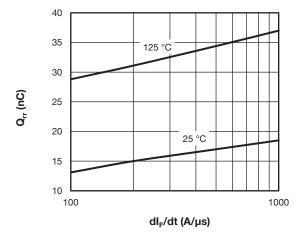


Fig. 7 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

Pd = forward power loss =  $I_{F(AV)} \times V_{FM}$  at ( $I_{F(AV)}/D$ ) (see fig. 5); Pd<sub>REV</sub> = inverse power loss =  $V_{R1} \times I_R$  (1 - D);  $I_R$  at  $V_{R1}$  = rated  $V_R$ 

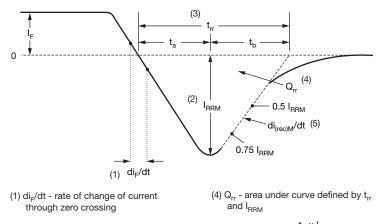
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## VS-1EFH01HM3

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(2)  ${\rm I}_{\rm RRM}$  - peak reverse recovery current

(3) t<sub>rr</sub> - reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75 I<sub>RRM</sub> and 0.50 I<sub>RRM</sub> extrapolated to zero current.  $Q_{rr} = \frac{t_{rr} \times l_{RRM}}{2}$  (5) di<sub>(rec)M</sub>/dt - peak rate of change of

current during  $t_b$  portion of  $t_{rr}$ 

Fig. 8 - Reverse Recovery Waveform and Definitions

#### **ORDERING INFORMATION TABLE**

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Device code	VS-	1	E	F	н	01	н	М3
	1	2	3	4	5	6	7	8
	1	- Vis	hay Sen	nicondu	ctors pr	oduct		
	2	- Cui	rrent rati	ing (1 =	1 A)			
	3	- Cire	cuit con	figuratio	n:			
		E =	single o	diode				
	4	- F=	SMF pa	ackage				
	5	- Pro	cess typ	ce,				
		H =	hyperfa	ast recov	very			
	6	- Vol	tage co	de (01 =	100 V)			
	7	- H=	AEC-Q	101 qua	alified			
	8	- M3	= halog	en-free,	RoHS-	complia	ant, and	termina

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-1EFH01HM3/I	10 000	10 000	13"diameter plastic tape and reel				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95572				
Part marking information	www.vishay.com/doc?95618				
Packaging information	www.vishay.com/doc?95577				
SPICE model	www.vishay.com/doc?96012				

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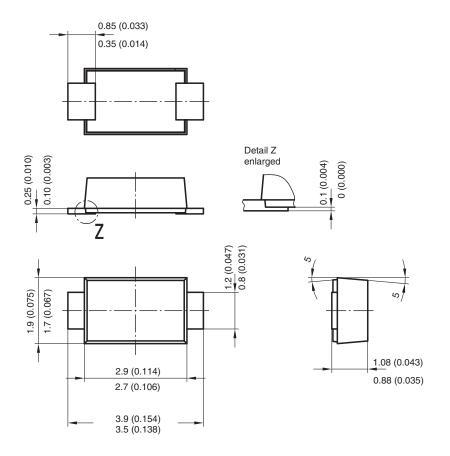
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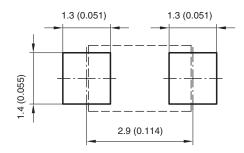
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# SMF (DO-219AB)

#### **DIMENSIONS** in millimeters (inches)



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